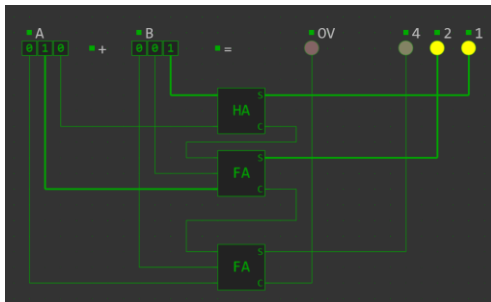
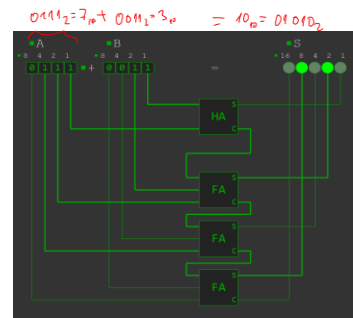
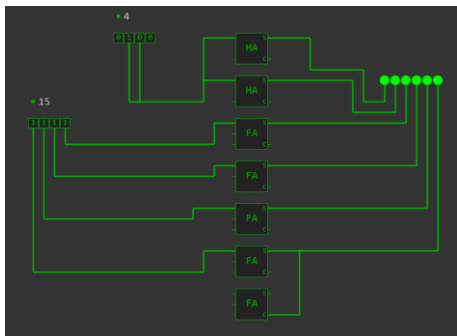




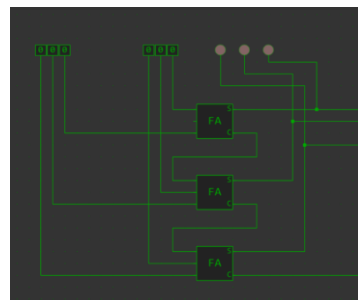
1



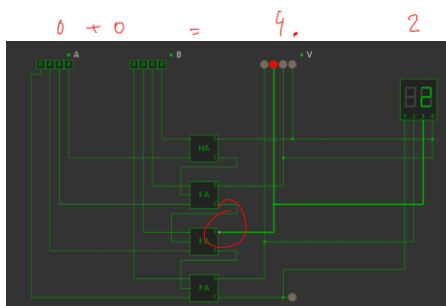
2



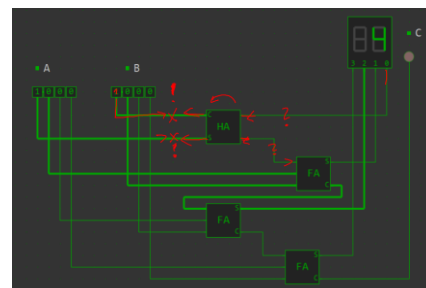
3



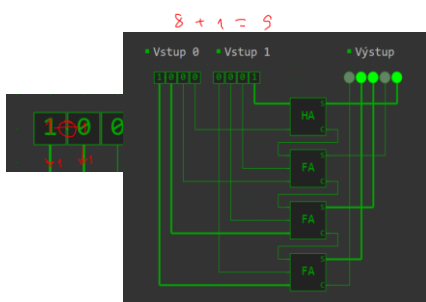
4



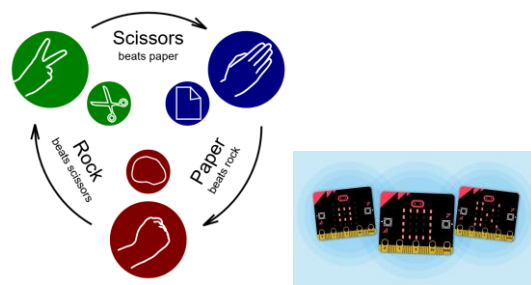
5



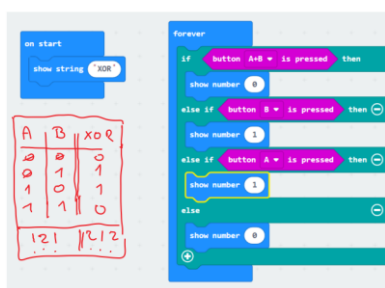
6



7



8



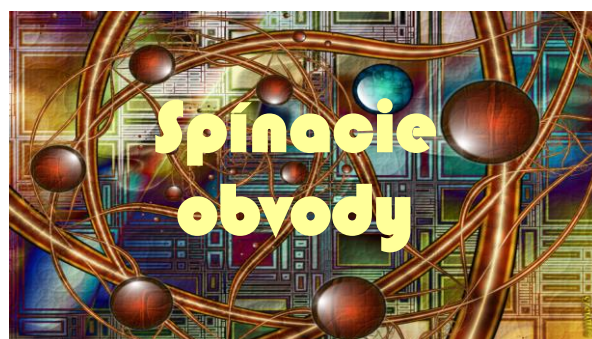
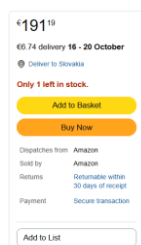
9



10



11



12

Dnes sa naučíme

- Pochopiť, z čoho stavíme logické členy
- Rozdiel medzi mechanickým a elektronickým spínačom
- Ako funguje tranzistor
- Dozvedieť sa ako sa vyrába integrovaný obvod
- Ako je to s rýchlosťou a ako kresliť časové diagramy

13

Spínač



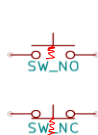
Source: Wikipedia

14

Spínač

NO – Normally Open
NC – Normally Closed
SPST – Single Pole Single Throw
SPDT – Single Pole Double Throw
DPST – Double pole Single Throw

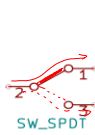
Otvorený v kľudovom stave
Zatvorený v kľudovom stave
Jednopolový vypínač
Striedavý prepínač
Dvojpolový vypínač



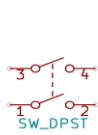
tlačidlo



jedenpolový vypínač



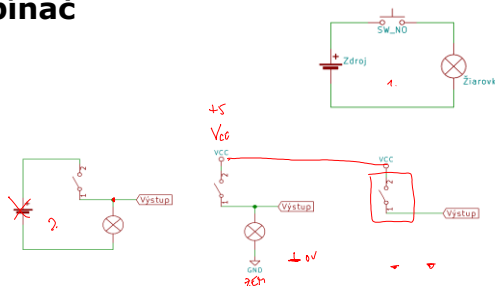
striedavý prepínač



dvojpolový vypínač

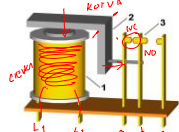
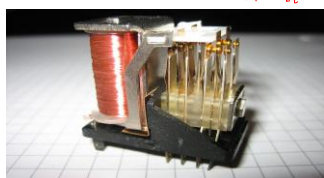
15

Spínač



16

Relé



1. Cievka (coil)
2. Kotva (armature)
3. Kontakt (contact)

Source: Wikipedia

17

Panasonic

ideas for life



MINI-ISO AUTOMOTIVE RELAY

CB RELAYS

FEATURES

- This relay has a Mini-ISO (International Organization for Standardization) terminal arrangement.
- Relay is compact and high capacity (40 A).
- Compact form factor realized with space saving 22 x 26 mm (0.86 x 1.024 inch) small base area thanks to integrated bobbin and base construction. Features high switching capacity of 40 A.

TYPICAL APPLICATIONS

- Automobiles
Headlights, Cell motors, Air conditioners, ABS, EPS, etc.
- Construction equipment
• Agricultural equipment, Conveyor, etc.

characteristics	Vibration	Functional	10 Hz to 500 Hz, Min. 44.1m/s ² (4.5G)
Expected life	Destructive		10 Hz to 2,000 Hz, Min. 44.1m/s ² (4.5G) for each direction: X, Y, Z direction: 4 hours
	Electrical (at nominal switching capacity)		Flux-resistant type: Min. 10 ⁷ ; Seal type: Min. 5-10 ⁶ (Operating frequency: 2s ON, 2s OFF)
	Mechanical		Min. 10 ⁶ (at 120 rpm)
Conditions for operation, transport and storage			Standard type: Ambient temperature: -40 to +85°C (-40 to +181°F) Humidity: 5 to 85% R.H. (not freezing and condensing at low temperature)

18

Claude Elwood Shannon

* 30. apríla 1916, Michigan
† 24. február 2001, Massachusetts

– profesor na MIT

Kybernetika, Teória informácie, Entropia

Symbolická analýza zmeny a spínacie obvody

Bell Labs Inc. - reléová logika



Source: Wikipedia, <http://cyberneticzoo.com>

19

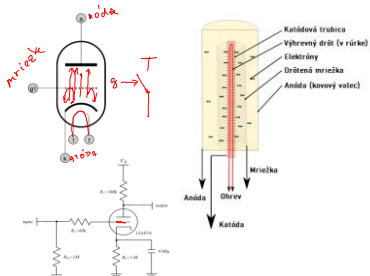
Theseus (1952) Maze-Solving Mouse



Source: <http://cyberneticzoo.com>

20

Elektrónka



Source: Wikipedia

21

Elektrónka



ENIAC (1946)

- 17 468 elektróniek
- $P = 150$ kW
- $m = 27\,000$ kg
- $2,4 \times 0,9 \times 30$ m
- \$487,000
(ekv. 2016: \$6,740,000)

Source: Wikipedia

22

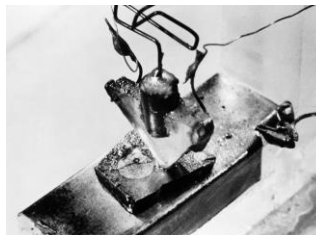
Elektrónky r. 2025



Source: McIntosh Laboratory

23

Tranzistor



Bell Labs

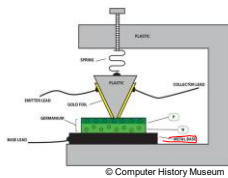
John Bardeen
Walter Brattain
William Shockley

Nobelova cena 1956

Source: Wikipedia

24

Tranzistor



© Computer History Museum



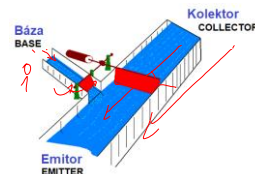
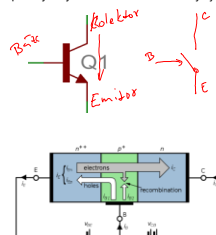
Source: Wikipedia

1939: William Shockley (AT&T's Bell Labs) myšlienka náhrady elektróniek
 1947: Shockley → John Bardeen and Walter Brattain prvý reálny tranzistorový zosilňovač
 1956: Nobelova cena pre všetkých troch

25

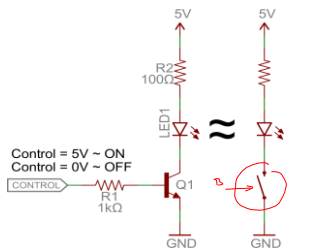
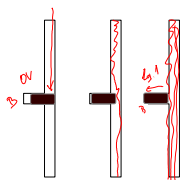
Tranzistor bipolárny, NPN

Bipolárny – využíva ako nosiče elektróny aj diery



26

Tranzistor



© Sparkfun

27

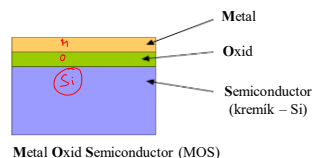
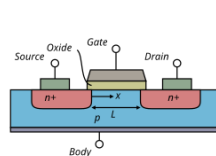
Poľom riadené tranzistory (unipolárne)

FET – Field Effect Transistor

MOS Metal, Oxid, Semiconductor – technológia

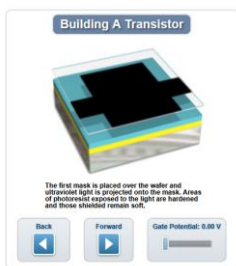
MOSFET – základný typ používaný v integrovaných obvodoch

Nosič náboja je len jeden



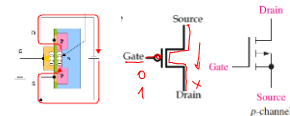
Metal Oxid Semiconductor (MOS)

28


<https://micro.rpi.edu/electromag/java/transistor/>

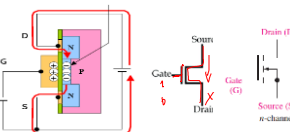
29

Tranzistor PMOS a NMOS (MOS tranzistor s kanálom P a N)



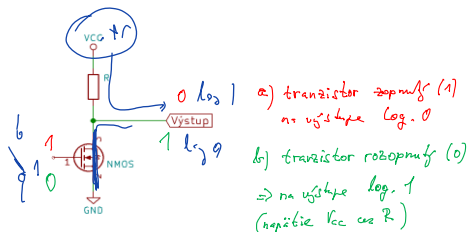
G – gate / hradlo
 D – drain / kolektor
 S – source / emitor

- historicky najstaršia technológia
- nízka rýchlosť
- zlá zlučiteľnosť s TTL (bipolárnymi) obvodmi



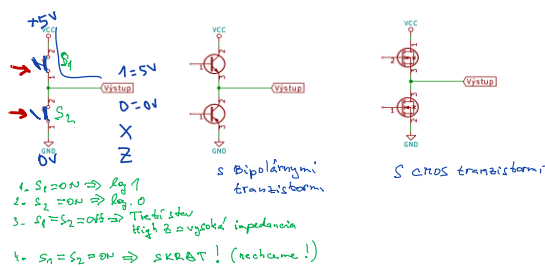
- rýchlosť je vyššia
- zlučiteľné s TTL
- vyššie straty

30



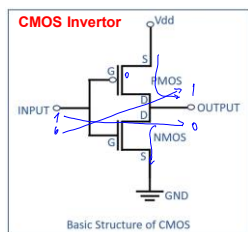
31

Totem pole



32

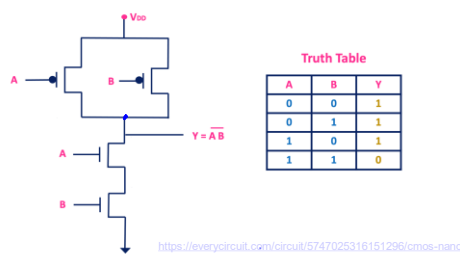
Technológia CMOS (Complementary MOS)



Výhody:
minimalizované straty
zlučiteľné s TTL

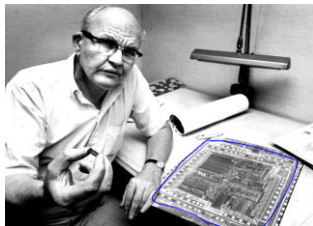
33

NAND technológiou CMOS



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Integrovaný obvod



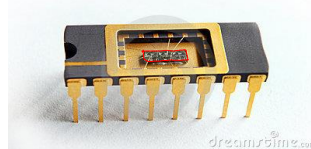
12. 9. 1958
Americký fyzik Jack Kilby vytvoril prvý integrovaný obvod na jednom čipe
@ Texas Instruments

2000 - Nobel Prize in physics



35

Integrovaný obvod



Name	Signification	Year	Transistors number ^[17]	Logic gates number ^[18]
SSI	small-scale integration	1964	1 to 10	1 to 12
MSI	medium-scale integration	1968	10 to 500	13 to 99
LSI	large-scale integration	1971	500 to 20,000	100 to 9,999
VLSI	very large-scale integration	1980	20,000 to 1,000,000	10,000 to 99,999
ULSI	ultra-large-scale integration	1984	1,000,000 and more	100,000 and more

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Moorov zákon

Gordon Moore

spoluzakladateľ firm Intel
a Fairchild Semiconductor

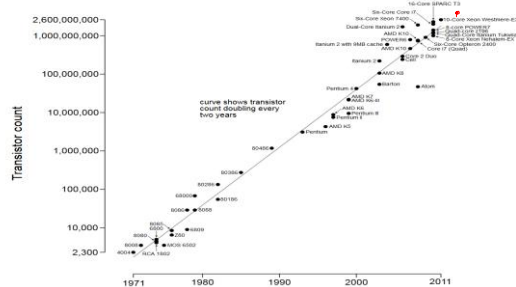


Moore's law is the observation:

*The number of transistors in a dense integrated circuit **doubles** approximately every **two years** (1965)*

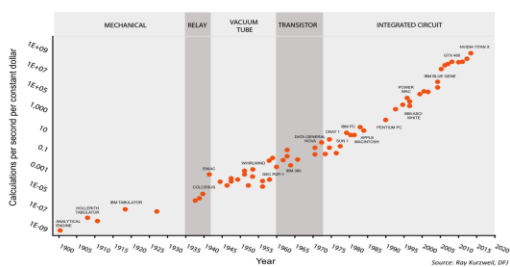
37

Moorov zákon



38

120 Years of Moore's Law



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slido
#ZPOC

Ak by sa automobilový priemysel rozvíjal rovnako
ako počítačový, aká by bola rýchlosť dnešných áut?

40

Moorov zákon

Ak by sa rovnako rozvíjal automobilový priemysel:

300 000 km/h

850 000 km / liter

0,04 \$ / ks



41

7400

TTL (Transistor-Transistor-Logic)

Integrovaný obvod 4x 2-vst. NAND

Technológia SSI – obsahuje cca **16 tranzistorov** a ďalšie súčiastky

Cena cca 0,30 \$ ale bola aj 22\$ r. 1965

FAIRCHILD
SEMICONDUCTOR™
DM74LS00
Quad 2-Input NAND Gate

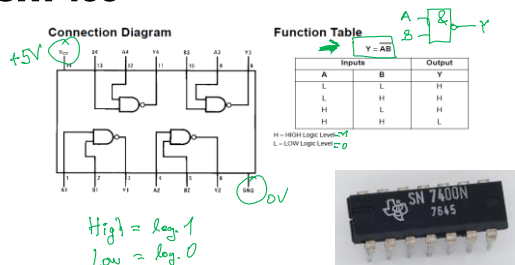


Nie Intel Core i5-7400 Quad-Core, 3.0 GHz (65 W),
TurboBoost 3.5 GHz, Intel HD Graphics 630 (1500
MHz), 6 MB L3 cache, socket 1151. Káby lake 14 nm
182-, USD Transistorov: 790 000 000



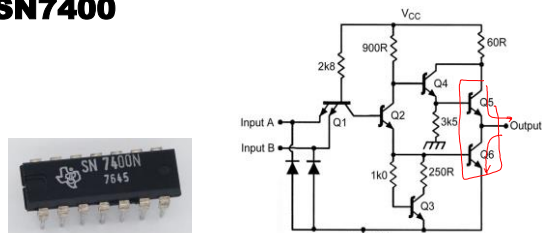
42

SN7400



43

SN7400



<https://everycircuit.com/circuit/4806653265714176/ttl-standard-nand-logic-gate>

<https://www.falstad.com/circuit/index.html>

44

DM74LS00

Absolute Maximum Ratings (Note 1)

Supply Voltage: V_{CC}

Input Voltage: V_{in}

Operating Free Air Temperature Range: 0°C to $+70^{\circ}\text{C}$

Storage Temperature Range: -65°C to $+150^{\circ}\text{C}$

Recommended Operating Conditions

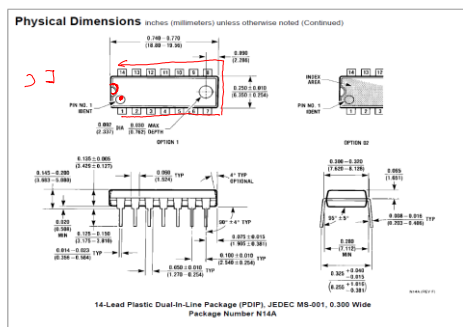
Symbol	Parameter	Min	Typ	Max	Units
V_{CC}	Supply Voltage	5.0	5.5	5.5	V
V_{in}	Input Voltage	0.0	5.5	5.5	V
V_{OL}	LOW Level Output Voltage	0.0	0.4	0.4	V
I_{OL}	LOW Level Output Current	0	8	8	mA
T_A	Free Air Operating Temperature	0	70	70	$^{\circ}\text{C}$

Electrical Characteristics

over recommended operating free air temperature range (unless otherwise noted)

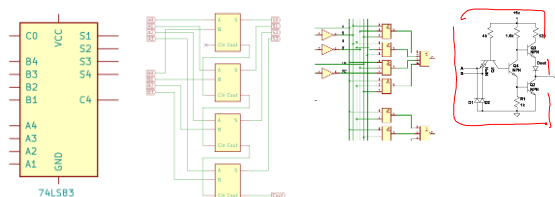
Symbol	Parameter	Conditions	Min	Typ	Max	Units
V_{in}	Input Clamping Voltage	$V_{CC} = \text{Min}, I_C = -10 \text{ mA}$		2.7	3.4	V
V_{OL}	LOW Level Output Voltage	$V_{CC} = \text{Max}, V_i = \text{Max}, I_{OL} = \text{Max}$	0.0	0.4	0.4	V
I_{in}	Input Current @ Max Input Voltage	$V_{CC} = \text{Max}, V_i = V_{CC}$	0	0.1	0.1	mA
I_{OL}	LOW Level Output Current	$V_{CC} = \text{Max}, V_i = 0 \text{ V}$	0	8	8	mA
I_{CC}	Supply Current with Outputs Volged	$V_{CC} = \text{Max}$	0	0.8	1.0	mA

45



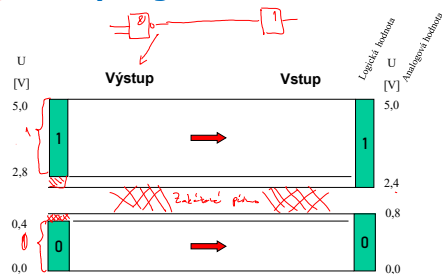
46

Štvorbítová sčítačka – princíp čiernej skrinky



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TTL obvody: logické úrovne



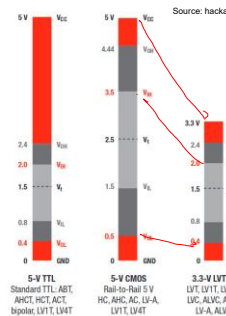
48

Logické úrovne CMOS

log. 0 = 0,0 až $0,3 \times V_{DD}$
 log. 1 = $0,7 \times V_{DD}$ až V_{DD}

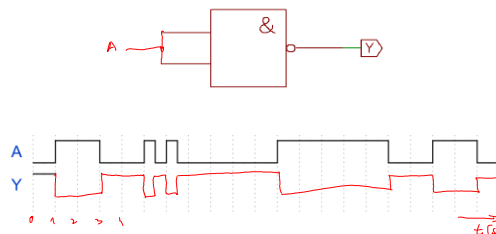
Ak je $V_{DD} = 5,0 \text{ V}$
 log. 0 je 0,0 až 1,5 V
 log. 1 je 3,5 až 5,0 V

Okrem 5,0 V používa CMOS aj
 $V_{DD} = 3,3$ alebo 1,8 V a pod.



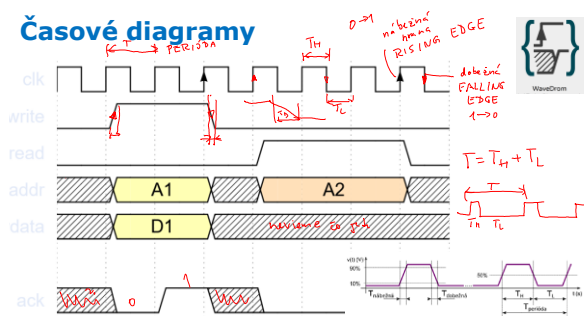
49

Časové diagramy



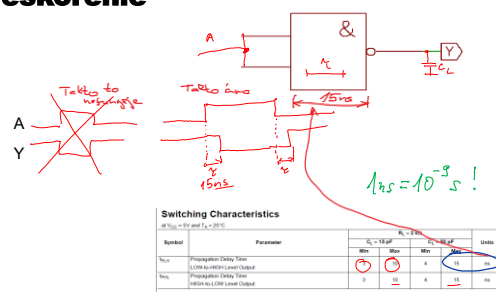
50

Časové diagramy



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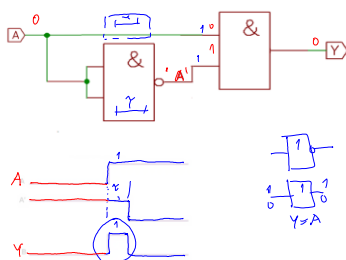
Oneskorenie



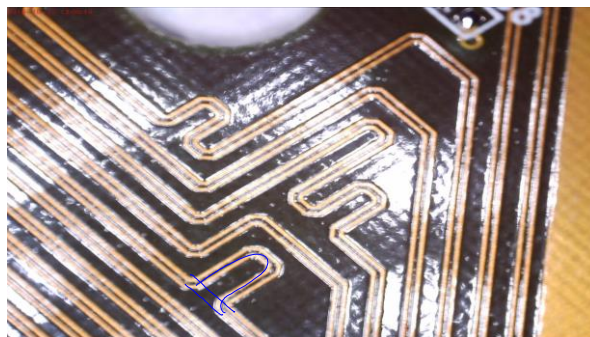
Symbol	Parameter	VDD = 5.0V		Units
		Min	Max	
t _{pd}	Propagation Delay Time	15	15	ns
t _{su}	Setup Time	10	10	ns
t _{ho}	Hold Time	10	10	ns

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Zákmity / glitch

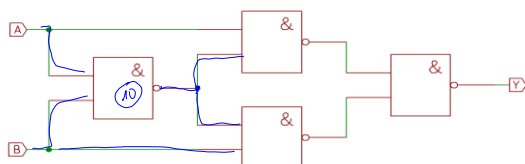


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54

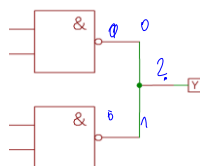
Spájanie vstupov a výstupov



Vstupy: OK

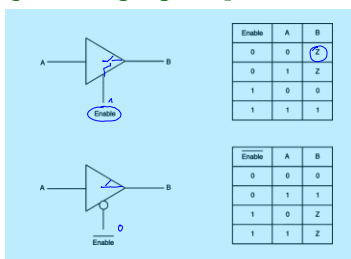
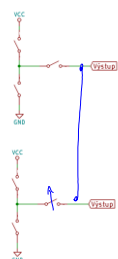
55

Spájanie výstupov



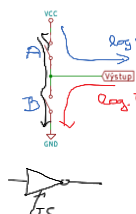
56

Zbernice – trojstavový výstup H, Z



57

Zbernice – trojstavový výstup



$A \text{ rozpnú } B \text{ rozpnú } = \text{Log } 1$
 $A \text{ rozpnú } B \text{ rozpnú } = \text{Log } 0$
 $A \text{ z } B \text{ rozpnú } = \text{stav vysoký impedance}$
 High Z
 alebo tiež stav
 (obvod je odpojený)
 $A \text{ z } B \text{ rozpnú } = \text{SUCCES !}$
 násme náske

58

slidoc
#ZPOC

Ako funguje tranzistor, aké má výhody
oproti mechanickému spínaču.

Rozumiem a vedel
by som to aj vy-
svetliť kamošovi



Pochopil som to



Pochopil, ale
musím si to ešte
pozrieť



Dnes teda nič...



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Zhrnutie 1-3

- Číslková logika (0, 1, De Morganove pravidlá)
- Logické členy (NOT, AND, OR, NAND, NOR, XOR)
- Opis logických obvodov (schéma, tabuľka, rovnica, K-mapa) *o.c. diagram*
- Analýza (schéma, tabuľka, rovnica)
- Syntéza (schéma, tabuľka, rovnica), simulácia a realizácia
- Spínacie prvky (relé, tranzistor, TTL obvody)

60

Chcem vedieť viac...

John F. WAKERLY:
Digital design.
 Stanford University : Prentice Hall, 2006.



Jean-Michel BERNARD, Jean HUGON
 a Robert Le Corvec:
Od logických obvodů k mikroprocesorům.
 SNTL : Praha, 1982

